



A62S9308 Series

Preliminary

512K X 8 BIT LOW VOLTAGE CMOS SRAM

Document Title

512K X 8 BIT LOW VOLTAGE CMOS SRAM

Revision History

| <u>Rev. No.</u> | <u>History</u> | <u>Issue Date</u> | <u>Remark</u> |
|-----------------|----------------|-------------------|---------------|
| 0.0 | Initial issue | February 12, 2001 | Preliminary |



A62S9308 Series

Preliminary

512K X 8 BIT LOW VOLTAGE CMOS SRAM

Features

- Power supply range: 2.7V to 3.6V
- Access times: 70 ns (max.)
- Current:
 - A62S9308-S series: Operating: 40mA (max.)
Standby: 10µA (max.)
 - A62S9308-SI series: Operating: 40mA (max.)
Standby: 15µA (max.)
- Extended operating temperature range: -25°C to 85°C for -SI series
- Full static operation, no clock or refreshing required
- All inputs and outputs are directly TTL compatible
- Common I/O using three-state output
- Output enable and two chip enable inputs for easy application
- Data retention voltage: 2V (min.)
- Available in 32-pin SOP, TSOP, sTSOP (8X 13.4mm) forward type and 36-ball Mini BGA (6X8) packages

General Description

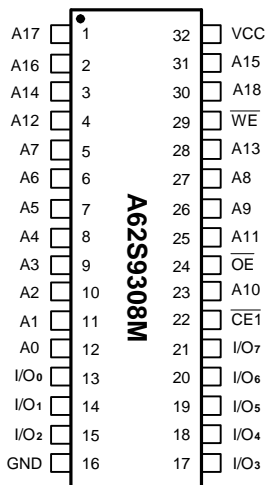
The A62S9308 is a low operating current 4,194,304-bit static random access memory organized as 524,288 words by 8 bits and operates on a low power supply voltage from 2.7V to 3.6V.

Inputs and three-state outputs are TTL compatible and allow for direct interfacing with common system bus structures.

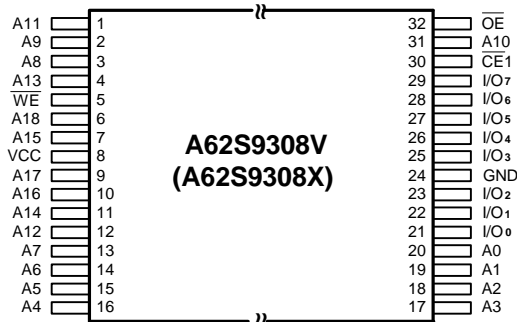
Two chip enable inputs for Mini BGA package are provided for power down and a device enable and an output enable input are included for easy interfacing. Data retention is guaranteed at a power supply voltage as low as 2V.

Pin Configurations

■ SOP

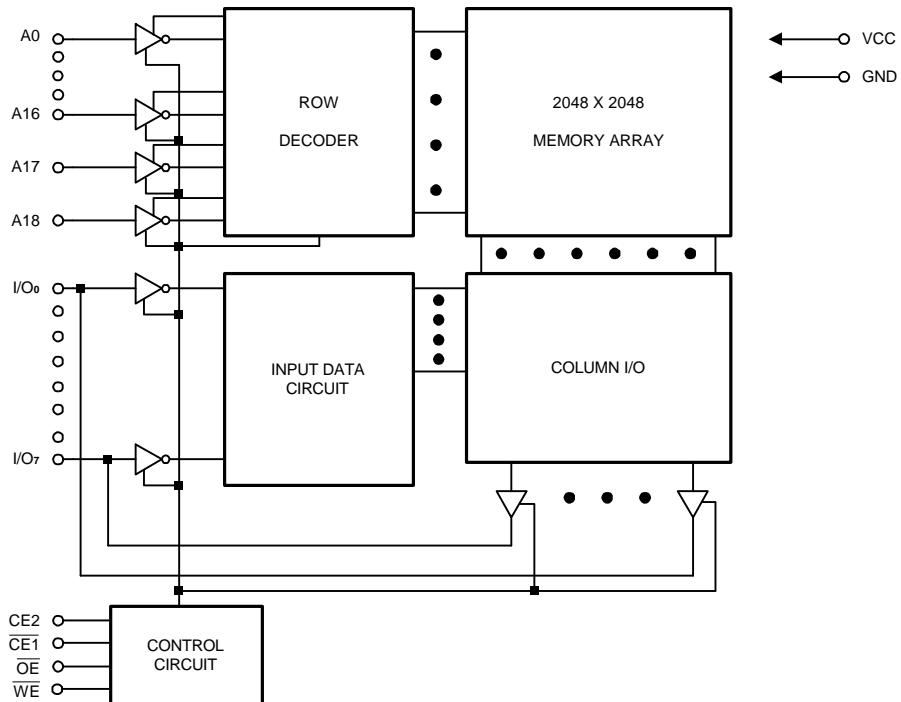


■ TSOP/(sTSOP) (forward type)



■ Mini BGA (6X8) Top View

| | 1 | 2 | 3 | 4 | 5 | 6 |
|---|------|-----|-----|-----|-----|------|
| A | A0 | A1 | CE2 | A3 | A6 | A8 |
| B | I/O4 | A2 | WE | A4 | A7 | I/O0 |
| C | I/O5 | | NC | A5 | | I/O1 |
| D | VSS | | | | | VCC |
| E | VCC | | | | | VSS |
| F | I/O6 | | A18 | A17 | | I/O2 |
| G | I/O7 | OE | CE1 | A16 | A15 | I/O3 |
| H | A9 | A10 | A11 | A12 | A13 | A14 |

Block Diagram

Pin Descriptions - SOP

| Pin No. | Symbol | Description |
|-----------------------------|-------------------------------------|---------------------|
| 1 - 12, 23, 25 - 28, 30, 31 | A0 - A18 | Address Inputs |
| 13 - 15, 17 - 21 | I/O ₀ - I/O ₇ | Data Inputs/Outputs |
| 16 | GND | Ground |
| 22 | $\overline{\text{CE1}}$ | Chip Enable 1 |
| 24 | $\overline{\text{OE}}$ | Output Enable |
| 29 | $\overline{\text{WE}}$ | Write Enable |
| 32 | VCC | Power Supply |

Pin Description - TSOP/sTSOP

| Pin No. | Symbol | Description |
|-------------------------|-------------------------------------|---------------------|
| 1 - 4, 6, 7, 9 - 20, 31 | A0 - A18 | Address Inputs |
| 5 | $\overline{\text{WE}}$ | Write Enable |
| 8 | VCC | Power Supply |
| 21 - 23, 25 - 29 | I/O ₀ - I/O ₇ | Data Inputs/Outputs |
| 24 | GND | Ground |
| 30 | $\overline{\text{CE1}}$ | Chip Enable 1 |
| 32 | $\overline{\text{OE}}$ | Output Enable |

Recommended DC Operating Conditions

 (T_A = 0°C to +70°C or -25°C to 85°C)

| Symbol | Parameter | Min. | Typ. | Max. | Unit |
|-----------------|--------------------|------|------|-----------|------|
| VCC | Supply Voltage | 2.7 | 3.0 | 3.6 | V |
| GND | Ground | 0 | 0 | 0 | V |
| V _{IH} | Input High Voltage | 2.4 | - | VCC + 0.3 | V |
| V _{IL} | Input Low Voltage | -0.3 | - | +0.6 | V |
| C _L | Output Load | - | - | 30 | pF |
| TTL | Output Load | - | - | 1 | - |

Absolute Maximum Ratings*

VCC to GND -0.5V to + 4.6V
 IN, IN/OUT Volt to GND -0.5V to VCC + 0.5V
 Operating Temperature, Topr -25°C to + 85°C
 Storage Temperature, Tstg -55°C to + 125°C
 Power Dissipation, P_T 0.7W
 Soldering Temp. & Time 260°C, 10 sec

***Comments**

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to this device. These are stress ratings only. Functional operation of this device at these or any other conditions above those indicated in the operational sections of this specification is not implied or intended. Exposure to the absolute maximum rating conditions for extended periods may affect device reliability.

DC Electrical Characteristics (T_A = 0°C to +70°C or -25°C to 85°C, VCC = 2.7V to 3.6V, GND = 0V)

| Symbol | Parameter | A62S9308-70S | | A62S9308-70SI | | Unit | Conditions |
|------------------|-----------------------------|--------------|------|---------------|------|------|--|
| | | Min. | Max. | Min. | Max. | | |
| I _{LI} | Input Leakage Current | - | 1 | - | 1 | μA | V _{IN} = GND to VCC |
| I _{LO} | Output Leakage Current | - | 1 | - | 1 | μA | $\overline{CE1} = V_{IH}$ or $CE2 = V_{IL}$ or $\overline{OE} = V_{IH}$ or $\overline{WE} = V_{IL}$ V _{IO} = GND to VCC |
| I _{CC} | Active Power Supply Current | - | 3 | - | 3 | mA | $\overline{CE1} = V_{IL}$, CE2 = V _{IH} I _{VO} = 0mA |
| I _{CC1} | Dynamic Operating Current | - | 40 | - | 40 | mA | Min. Cycle, Duty = 100% $\overline{CE1} = V_{IL}$, CE2 = V _{IH} I _{VO} = 0mA |
| I _{CC2} | | - | 10 | - | 10 | mA | $\overline{CE1} = V_{IL}$, CE2 = V _{IH} V _{IH} = VCC, V _{IL} = 0V, f = 1MHz, I _{VO} = 0mA |

DC Electrical Characteristics (continued)

| Symbol | Parameter | A62S9308-70S | | A62S9308-70SI | | Unit | Conditions |
|------------------|------------------------------|--------------|------|---------------|------|------|---|
| | | Min. | Max. | Min. | Max. | | |
| I _{SB} | Standby Power Supply Current | - | 0.5 | - | 0.5 | mA | $\overline{CE1} = V_{IH}$ or $CE2 = V_{IL}$ |
| I _{SB1} | | - | 10 | - | 15 | μA | $\overline{CE1} \geq V_{CC} - 0.2V$ $CE2 \geq V_{CC} - 0.2V$ $V_{IN} \geq 0V$ |
| I _{SB2} | | - | 10 | - | 15 | μA | $CE2 \leq 0.2V$ $V_{IN} \geq 0V$ |
| V _{OL} | Output Low Voltage | - | 0.4 | - | 0.4 | V | I _{OL} = 2.1mA |
| V _{OH} | Output High Voltage | 2.4 | - | 2.4 | - | V | I _{OH} = -1.0mA |

Truth Table

| Mode | $\overline{CE1}$ | CE2 | \overline{OE} | \overline{WE} | I/O Operation | Supply Current |
|----------------|------------------|-----|-----------------|-----------------|------------------|---|
| Standby | H | X | X | X | High Z | I _{SB} , I _{SB1} |
| | X | L | X | X | High Z | I _{SB} , I _{SB2} |
| Output Disable | L | H | H | H | High Z | I _{CC} , I _{CC1} , I _{CC2} |
| Read | L | H | L | H | D _{OUT} | I _{CC} , I _{CC1} , I _{CC2} |
| Write | L | H | X | L | D _{IN} | I _{CC} , I _{CC1} , I _{CC2} |

Note: X = H or L

Capacitance (T_A = 25°C, f = 1.0MHz)

| Symbol | Parameter | Min. | Max. | Unit | Conditions |
|--------------------|--------------------------|------|------|------|-----------------------|
| C _{IN} * | Input Capacitance | | 6 | pF | V _{IN} = 0V |
| C _{I/O} * | Input/Output Capacitance | | 8 | pF | V _{I/O} = 0V |

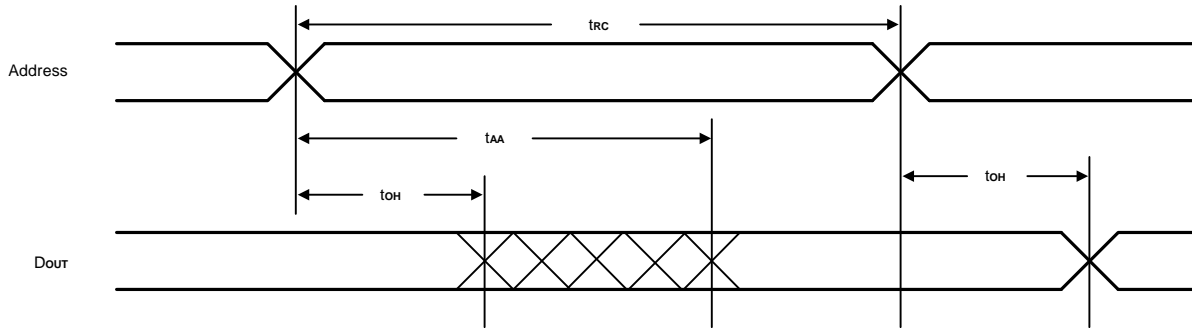
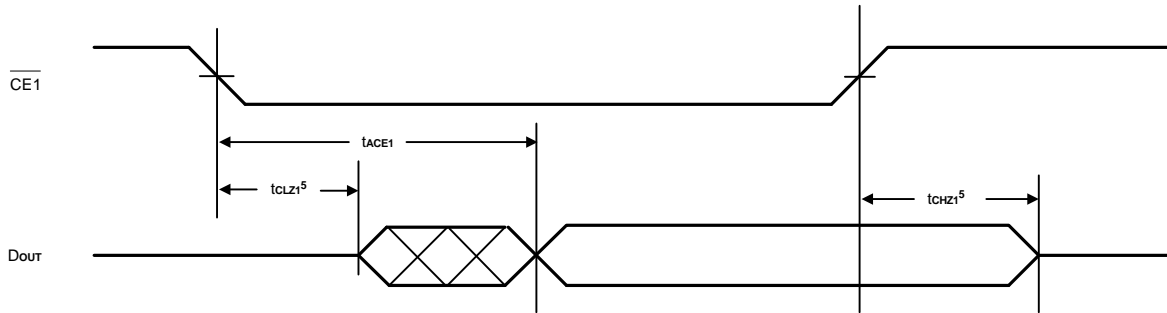
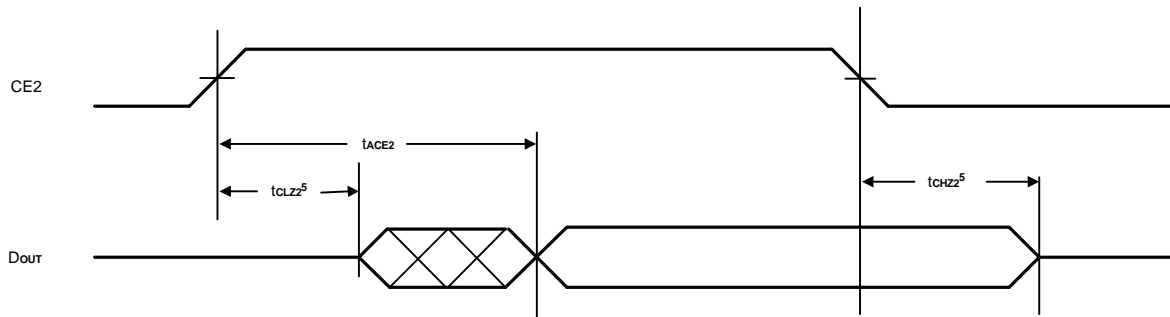
* These parameters are sampled and not 100% tested.

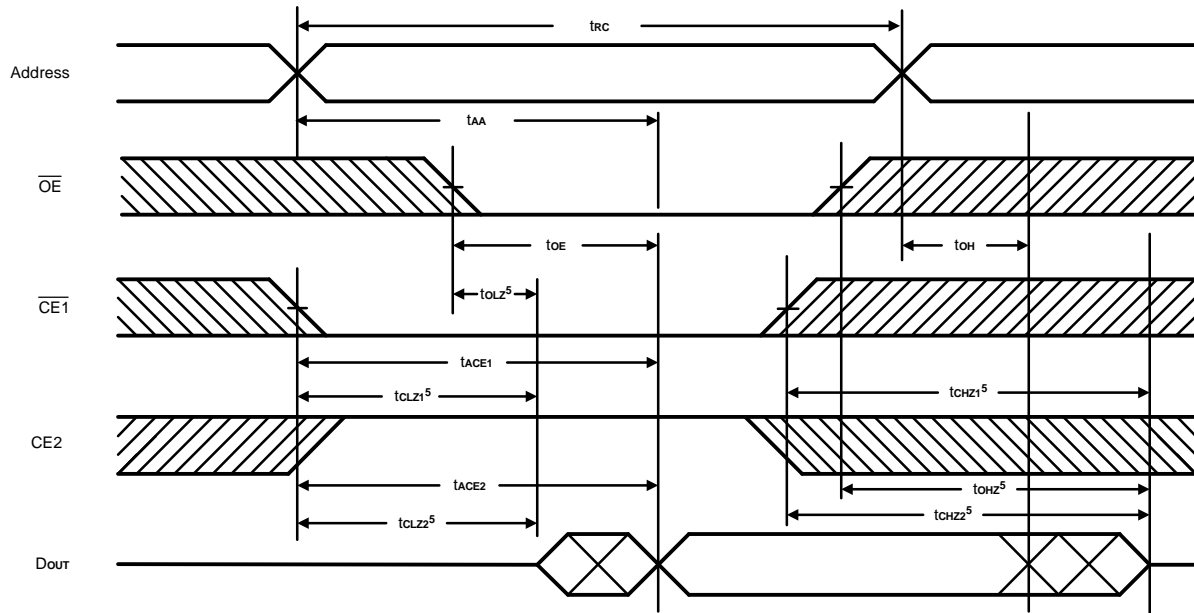


AC Characteristics ($T_A = 0^\circ\text{C}$ to $+70^\circ\text{C}$ or -25°C to 85°C , $V_{CC} = 2.7\text{V}$ to 3.6V)

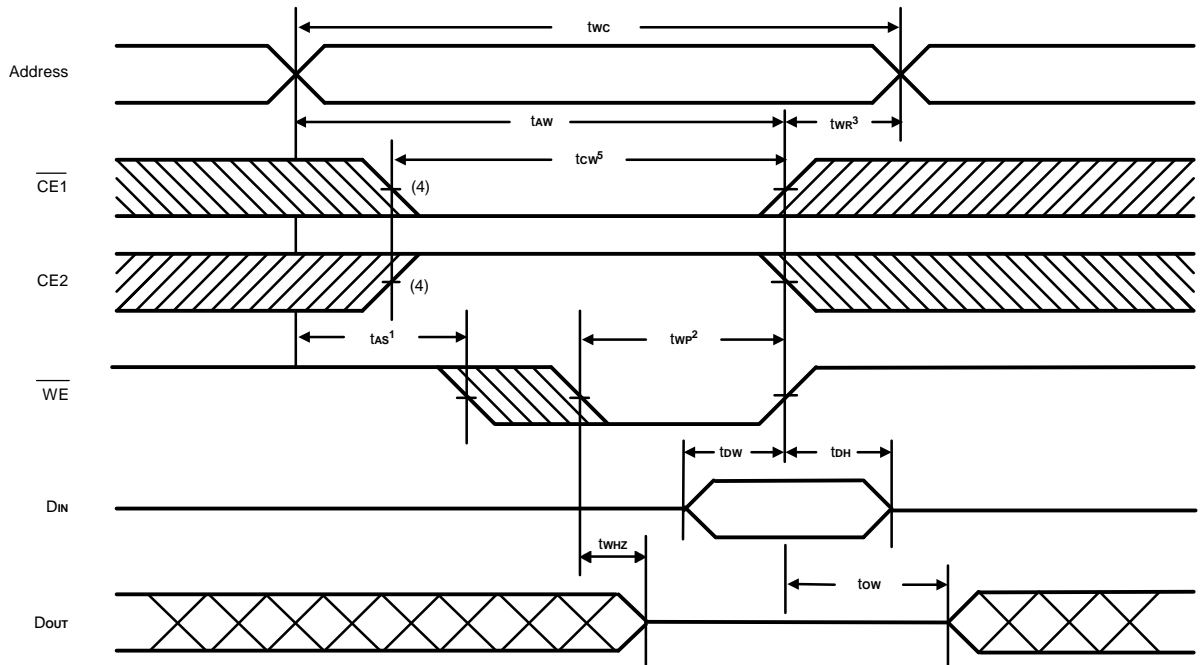
| Symbol | Parameter | | A62S9308-70S/SI | | Unit |
|-------------------|------------------------------------|-------------------------|-----------------|------|------|
| | | | Min. | Max. | |
| Read Cycle | | | | | |
| t _{rc} | Read Cycle Time | | 70 | - | ns |
| t _{AA} | Address Access Time | | - | 70 | ns |
| t _{ACE1} | Chip Enable Access Time | $\overline{\text{CE}}1$ | - | 70 | ns |
| t _{ACE2} | | CE2 | - | 70 | ns |
| t _{OE} | Output Enable to Output Valid | | - | 35 | ns |
| t _{CLZ1} | Chip Enable to Output in Low Z | $\overline{\text{CE}}1$ | 10 | - | ns |
| t _{CLZ2} | | CE2 | 10 | - | ns |
| t _{OLZ} | Output Enable to Output in Low Z | | 5 | - | ns |
| t _{CHZ1} | Chip Disable to Output in High Z | $\overline{\text{CE}}1$ | 0 | 25 | ns |
| t _{CHZ2} | | CE2 | 0 | 25 | ns |
| t _{OHZ} | Output Disable to Output in High Z | | 0 | 25 | ns |
| t _{OH} | Output Hold from Address Change | | 10 | - | ns |
| Read Cycle | | | | | |
| t _{wc} | Write Cycle Time | | 70 | - | ns |
| t _{cw} | Chip Enable to End of Write | | 60 | - | ns |
| t _{AS} | Address Setup Time | | 0 | - | ns |
| t _{AW} | Address Valid to End of Write | | 60 | - | ns |
| t _{WP} | Write Pulse Width | | 50 | - | ns |
| t _{WR} | Write Recovery Time | | 0 | - | ns |
| t _{WHZ} | Write to Output in High Z | | 0 | 25 | ns |
| t _{DW} | Data to Write Time Overlap | | 30 | - | ns |
| t _{DH} | Data Hold from Write Time | | 0 | - | ns |
| t _{OW} | Output Active from End of Write | | 5 | - | ns |

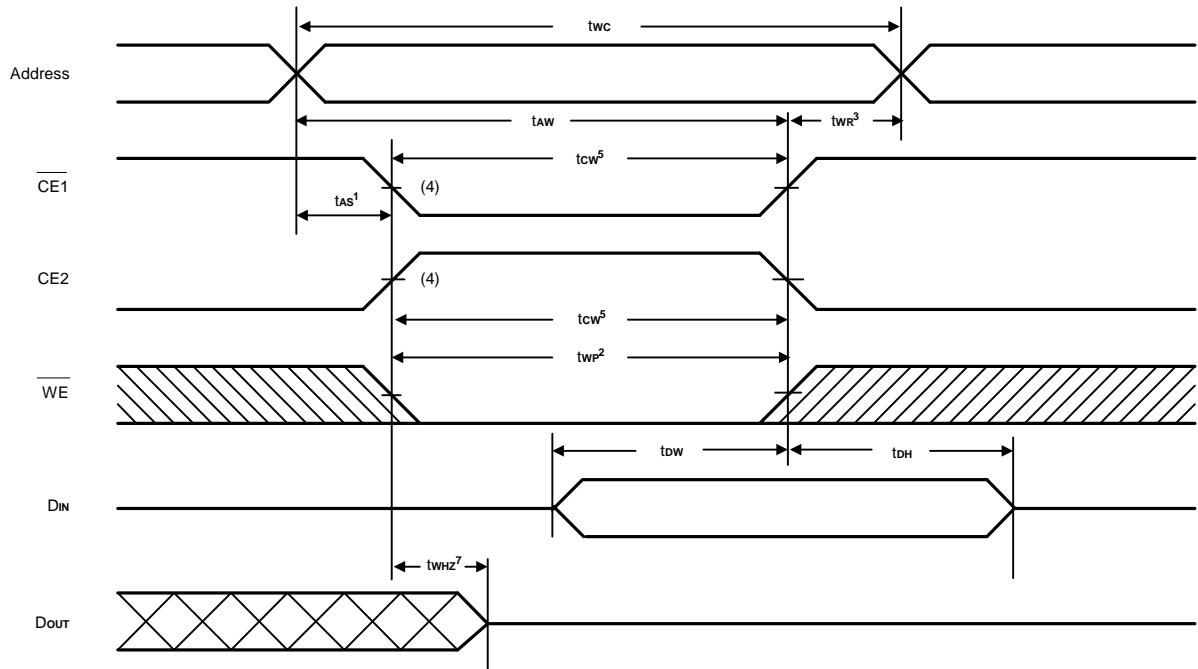
Notes: t_{CHZ1}, t_{CHZ2}, t_{OHZ} and t_{WHZ} are defined as the time at which the outputs achieve the open circuit condition and are not referred to output voltage levels.

Timing Waveforms
Read Cycle 1^(1, 2, 4)

Read Cycle 2^(1, 3, 4, 6)

Read Cycle 3^(1, 4, 7, 8)


Timing Waveforms (continued)
Read Cycle 4 ⁽¹⁾


- Notes:
1. \overline{WE} is high for Read Cycle.
 2. Device is continuously enabled $\overline{CE1} = V_{IL}$ and $CE2 = V_{IH}$.
 3. Address valid prior to or coincident with $\overline{CE1}$ transition low.
 4. $\overline{OE} = V_{IL}$.
 5. Transition is measured $\pm 500\text{mV}$ from steady state. This parameter is sampled and not 100% tested.
 6. CE2 is high.
 7. $\overline{CE1}$ is low.
 8. Address valid prior to or coincident with CE2 transition high.

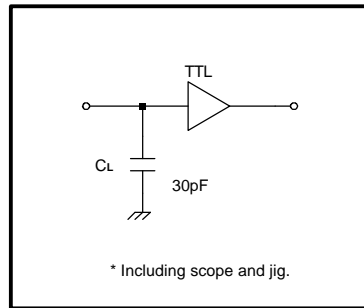
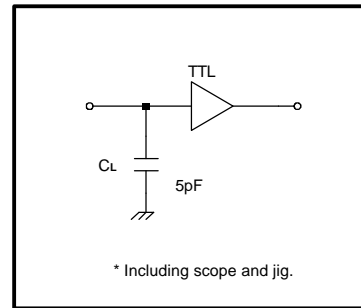
Timing Waveforms (continued)
Write Cycle 1⁽⁶⁾
(Write Enable Controlled)


Timing Waveforms (continued)
**Write Cycle 2
(Chip Enable Controlled)**


- Notes:
1. t_{AS} is measured from the address valid to the beginning of Write.
 2. A Write occurs during the overlap (t_{WP}) of a low $\overline{CE1}$, a high CE2 and a low \overline{WE} .
 3. t_{WR} is measured from the earliest of $\overline{CE1}$ or \overline{WE} going high or CE2 going low to the end of the Write cycle.
 4. If the $\overline{CE1}$ low transition or the CE2 high transition occurs simultaneously with the \overline{WE} low transition or after the \overline{WE} transition, outputs remain in a high impedance state.
 5. t_{CW} is measured from the later of $\overline{CE1}$ going low or CE2 going high to the end of Write.
 6. \overline{OE} is continuously low. ($\overline{OE} = V_{IL}$)
 7. Transition is measured $\pm 500\text{mV}$ from steady state. This parameter is sampled and not 100% tested.

AC Test Conditions

| | |
|--|---------------------|
| Input Pulse Levels | 0V to 3.0V |
| Input Rise and Fall Time | 5 ns |
| Input and Output Timing Reference Levels | 1.5V |
| Output Load | See Figures 1 and 2 |


Figure 1. Output Load

Figure 2. Output Load for t_{CLZ1} , t_{CLZ2} , t_{OHZ} , t_{OLZ} , t_{CHZ1} , t_{CHZ2} , t_{WHZ} , and t_{OW}
Data Retention Characteristics ($T_A = 0^\circ\text{C}$ to $+70^\circ\text{C}$ or -25°C to 85°C)

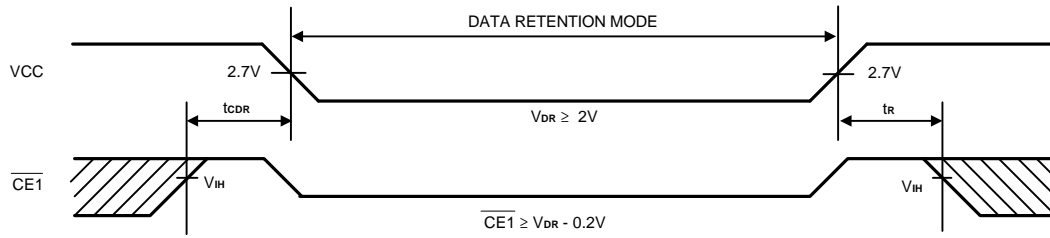
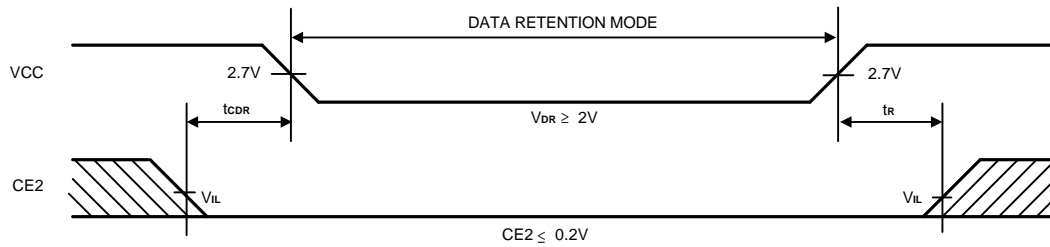
| Symbol | Parameter | Min. | Max. | Unit | Conditions |
|-------------|-------------------------------------|------------|------|------|--|
| V_{DR1} | VCC for Data Retention | 2.0 | 3.6 | V | $\overline{CE1} \geq V_{CC} - 0.2V$ |
| V_{DR2} | | 2.0 | 3.6 | V | $\overline{CE2} \leq 0.2V$ $\overline{CE1} \geq V_{CC} - 0.2V$ or $\overline{CE1} \leq 0.2V$ |
| I_{CCDR1} | Data Retention Current | S-Version | - | 5* | μA $V_{CC} = 2.0V$ $\overline{CE1} \geq V_{CC} - 0.2V$ $\overline{CE2} \geq V_{CC} - 0.2V$ $V_{IN} \geq 0V$ |
| | | SI-Version | - | 10** | |
| I_{CCDR2} | Data Retention Current | S-Version | - | 5* | μA $V_{CC} = 2.0V$ $\overline{CE2} \leq 0.2V$ $V_{IN} \geq 0V$ |
| | | SI-Version | - | 10** | |
| t_{CDR} | Chip Disable to Data Retention Time | 0 | - | ns | See Retention Waveform |
| t_r | Operation Recovery Time | t_{RC} | - | ns | |

* A62S9308-70S

I_{CCDR} : Max. $1\mu A$ at $T_A = 0^\circ\text{C} + 40^\circ\text{C}$

** A62S9308-70SI

I_{CCDR} : Max. $1\mu A$ at $T_A = 0^\circ\text{C} + 40^\circ\text{C}$

Low VCC Data Retention Waveform (1) ($\overline{CE1}$ Controlled)

Low VCC Data Retention Waveform (2) (CE2 Controlled)


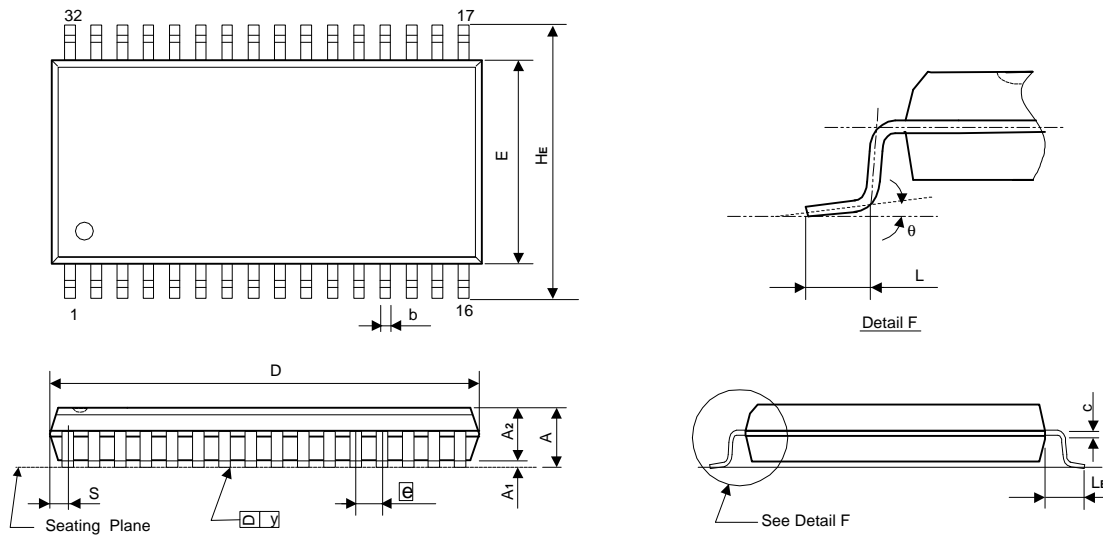


Ordering Information

| Part No. | Access Time (ns) | Operating Current Max. (mA) | Standby Current Max. (μA) | Package |
|-----------------|-----------------------------|--|--------------------------------------|----------------|
| A62S9308M-70S | 70 | 40 | 10 | 32L SOP |
| A62S9308M-70SI | | 40 | 15 | 32L SOP |
| A62S9308V-70S | | 40 | 10 | 32L TSOP |
| A62S9308V-70SI | | 40 | 15 | 32L TSOP |
| A62S9308X-70S | | 40 | 10 | 32L sTSOP |
| A62S9308X-70SI | | 40 | 15 | 32L sTSOP |
| A62S9308G-70S | | 40 | 10 | 36B Mini BGA |
| A62S9308G-70SI | | 40 | 15 | 36B Mini BGA |

Package Information
SOP (W.B.) 32L Outline Dimensions

unit: inches/mm



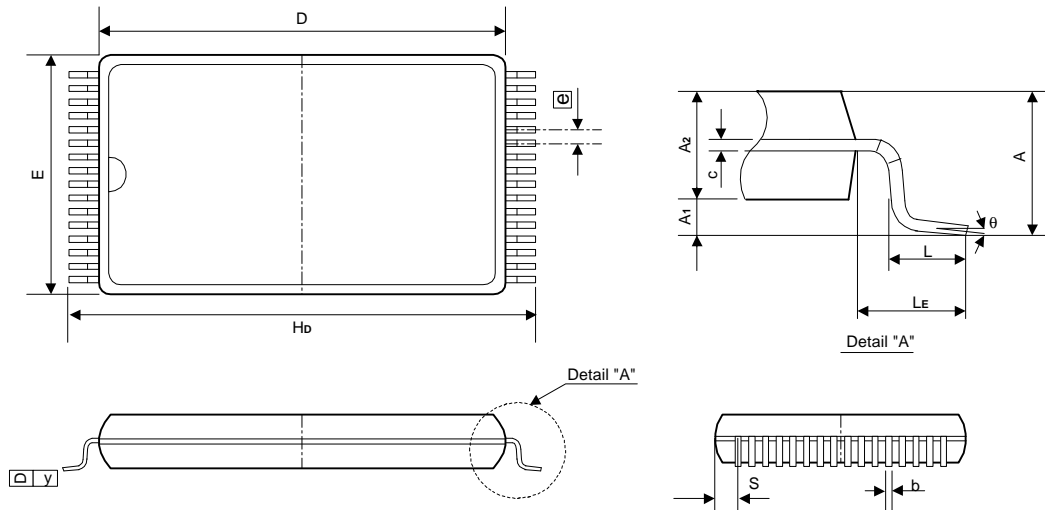
| Symbol | Dimensions in inches | | | Dimensions in mm | | |
|-----------|----------------------|-------|-------|------------------|-------|-------|
| | Min | Nom | Max | Min | Nom | Max |
| A | - | - | 0.118 | - | - | 3.00 |
| A1 | 0.004 | - | - | 0.10 | - | - |
| A2 | 0.101 | 0.106 | 0.111 | 2.57 | 2.69 | 2.82 |
| b | 0.014 | 0.016 | 0.020 | 0.36 | 0.41 | 0.51 |
| c | 0.006 | 0.008 | 0.012 | 0.15 | 0.20 | 0.31 |
| D | - | 0.805 | 0.817 | - | 20.45 | 20.75 |
| E | 0.440 | 0.445 | 0.450 | 11.18 | 11.30 | 11.43 |
| \bar{e} | 0.044 | 0.050 | 0.056 | 1.12 | 1.27 | 1.42 |
| HE | 0.546 | 0.556 | 0.566 | 13.87 | 14.12 | 14.38 |
| L | 0.023 | 0.031 | 0.039 | 0.58 | 0.79 | 0.99 |
| LE | 0.047 | 0.055 | 0.063 | 1.19 | 1.40 | 1.60 |
| S | - | - | 0.036 | - | - | 0.91 |
| y | - | - | 0.004 | - | - | 0.10 |
| θ | 0° | - | 10° | 0° | - | 10° |

Notes:

1. The maximum value of dimension D includes end flash.
2. Dimension E does not include resin fins.
3. Dimension S includes end flash.

Package Information
TSOP 32L TYPE I (8 X 20mm) Outline Dimensions

unit: inches/mm



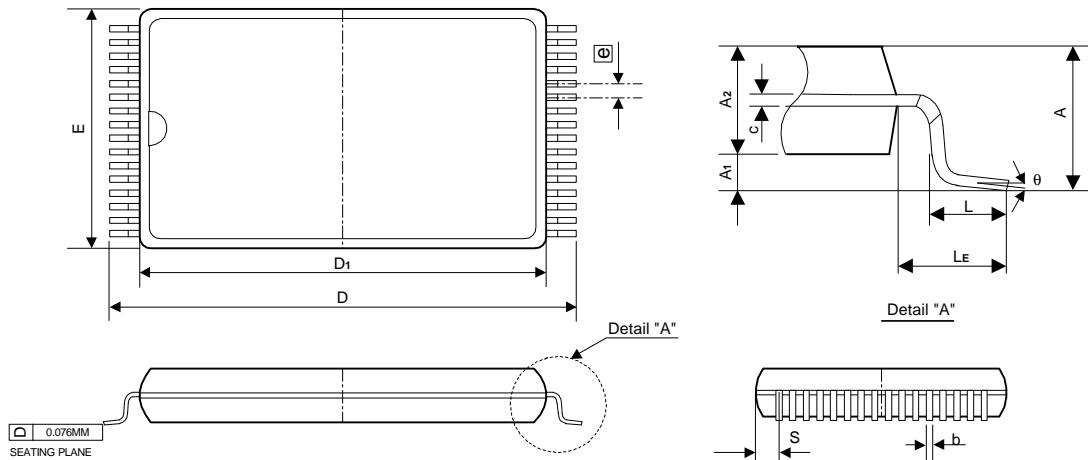
| Symbol | Dimensions in inches | | | Dimensions in mm | | |
|----------------|----------------------|-------|-------|------------------|-------|-------|
| | Min | Nom | Max | Min | Nom | Max |
| A | - | - | 0.047 | - | - | 1.20 |
| A ₁ | 0.002 | - | 0.006 | 0.05 | - | 0.15 |
| A ₂ | 0.037 | 0.039 | 0.041 | 0.95 | 1.00 | 1.05 |
| b | 0.007 | 0.009 | 0.011 | 0.18 | 0.22 | 0.27 |
| c | 0.004 | - | 0.008 | 0.11 | - | 0.20 |
| D | 0.720 | 0.724 | 0.728 | 18.30 | 18.40 | 18.50 |
| E | - | 0.315 | 0.319 | - | 8.00 | 8.10 |
| \square e | 0.020 BSC | | | 0.50 BSC | | |
| Hd | 0.779 | 0.787 | 0.795 | 19.80 | 20.00 | 20.20 |
| L | 0.016 | 0.020 | 0.024 | 0.40 | 0.50 | 0.60 |
| LE | - | 0.032 | - | - | 0.80 | - |
| S | - | - | 0.020 | - | - | 0.50 |
| y | - | - | 0.003 | - | - | 0.08 |
| θ | 0° | - | 5° | 0° | - | 5° |

Notes:

1. The maximum value of dimension D includes end flash.
2. Dimension E does not include resin fins.
3. Dimension S includes end flash.

Package Information
sTSOP 32L TYPE I (8 X 13.4mm) Outline Dimensions

unit: inches/mm



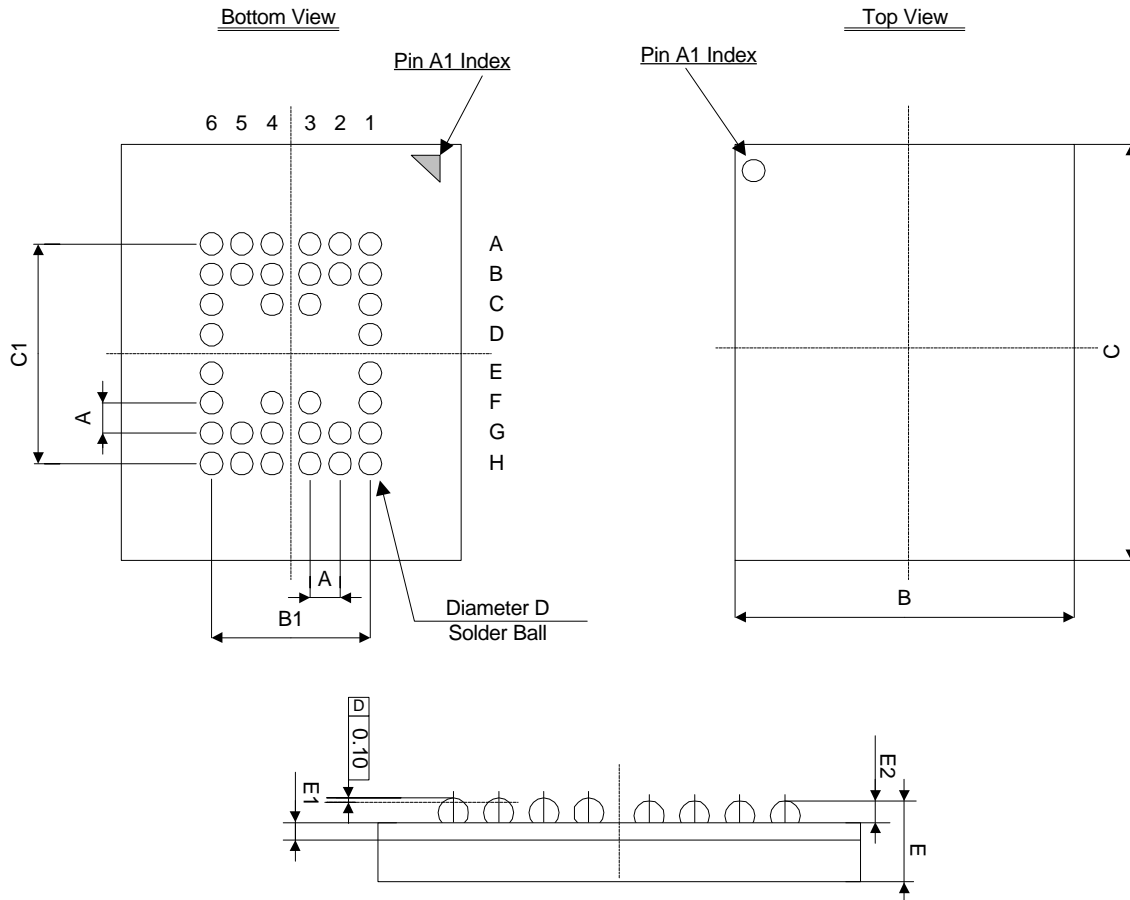
| Symbol | Dimensions in inches | | | Dimensions in mm | | |
|----------------|----------------------|--------|--------|------------------|-------|-------|
| | Min | Nom | Max | Min | Nom | Max |
| A | - | - | 0.049 | - | - | 1.25 |
| A ₁ | 0.002 | - | - | 0.05 | - | - |
| A ₂ | 0.037 | 0.039 | 0.041 | 0.95 | 1.00 | 1.05 |
| b | 0.007 | 0.008 | 0.009 | 0.17 | 0.20 | 0.23 |
| c | 0.0056 | 0.0059 | 0.0062 | 0.142 | 0.150 | 0.158 |
| E | 0.311 | 0.315 | 0.319 | 7.90 | 8.00 | 8.10 |
| e | 0.020 TYP | | | 0.50 TYP | | |
| D | 0.520 | 0.528 | 0.535 | 13.20 | 13.40 | 13.60 |
| D ₁ | 0.461 | 0.465 | 0.469 | 11.70 | 11.80 | 11.90 |
| L | 0.012 | 0.020 | 0.028 | 0.30 | 0.50 | 0.70 |
| LE | 0.0275 | 0.0315 | 0.0355 | 0.700 | 0.800 | 0.900 |
| S | 0.0109 TYP | | | 0.278 TYP | | |
| θ | 0° | 3° | 5° | 0° | 3° | 5° |

Notes:

1. The maximum value of dimension D₁ includes end flash.
2. Dimension E does not include resin fins.
3. Dimension S includes end flash.

Package Information
Mini BGA 6X8 (36 BALLS) Outline Dimensions

unit : millimeter(mm)



| Symbol | Min | Typ | Max |
|--------|------|------|------|
| A | - | 0.75 | - |
| B | 5.90 | 6.00 | 6.10 |
| B1 | - | 3.75 | - |
| C | 7.90 | 8.00 | 8.10 |
| C1 | - | 5.25 | - |
| D | 0.30 | 0.35 | 0.40 |
| E | 1.00 | 1.10 | 1.20 |
| E1 | - | 0.36 | - |
| E2 | - | 0.22 | - |